2SC3799, 2SC3799A

Silicon NPN triple diffusion planar type

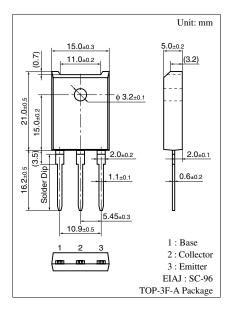
For high breakdown voltage high-speed switching

■ Features

- High-speed switching
- \bullet High collector to base voltage V_{CBO}
- ullet Low collector to emitter saturation voltage $V_{\text{CE(sat)}}$
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25$ °C

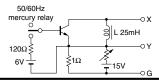
Parameter		Symbol	Rating	Unit
Collector to base	2SC3799	V_{CBO}	800	V
voltage	2SC3799A		900	
Collector to	2SC3799	V _{CES}	800	V
emitter voltage	2SC3799A		900	
Collector to emitter voltage		V _{CEO}	500	V
Emitter to base voltage		V_{EBO}	8	V
Peak collector current		I_{CP}	15	A
Collector current		I_{C}	7	A
Base current		I_B	4	A
Collector power	$T_C = 25^{\circ}C$	P_{C}	100	W
dissipation	$T_a = 25^{\circ}C$		3	
Junction temperature		T _j	150	°C
Storage temperature		T_{stg}	-55 to +150	°C

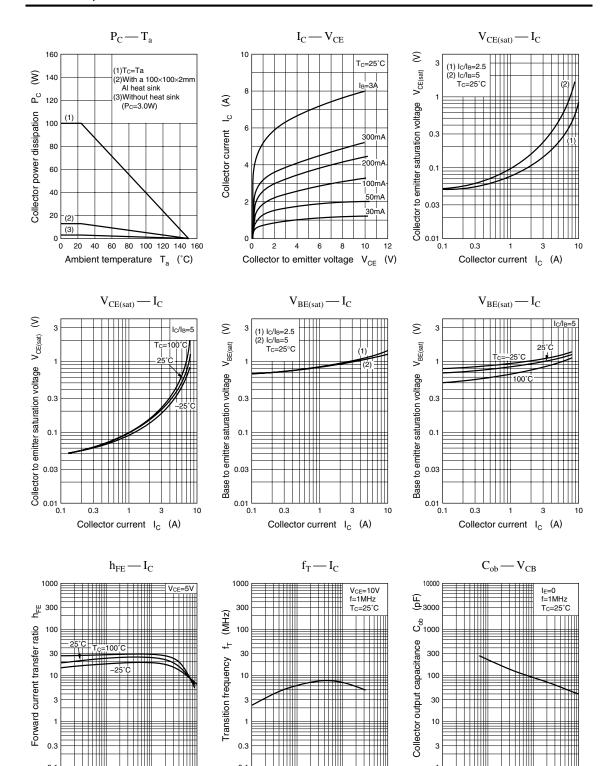


■ Electrical Characteristics $T_C = 25$ °C

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Collector cutoff	2SC3799	I_{CBO}	$V_{CB} = 800 \text{ V}, I_{E} = 0$			100	μΑ
current	2SC3799A		$V_{CB} = 900 \text{ V}, I_{E} = 0$			100	
Emitter cutoff current		I_{EBO}	$V_{EB} = 5 \text{ V}, I_{C} = 0$			100	μΑ
Collector to emitter voltage *		V _{CEO(sus)}	$I_C = 0.2 \text{ A}, L = 25 \text{ mH}$	500			V
Forward current transfer ratio		h _{FE1}	$V_{CE} = 5 \text{ V}, I_{C} = 0.1 \text{ A}$	15			
		h _{FE2}	$V_{CE} = 5 \text{ V}, I_{C} = 5 \text{ A}$	8			
Collector to emitter saturation voltage		V _{CE(sat)}	$I_{\rm C} = 5 \text{ A}, I_{\rm B} = 1 \text{ A}$			1	V
Base to emitter saturation voltage		V _{BE(sat)}	$I_C = 5 \text{ A}, I_B = 1 \text{ A}$			1.5	V
Transition frequency		f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.5 \text{ A}, f = 1 \text{ MHz}$		8		MHz
Turn-on time	2SC3799	t _{on}	$I_C = 5 \text{ A}, I_{B1} = 1 \text{ A}, I_{B2} = -1 \text{ A},$			1	μs
	2SC3799A		$V_{CC} = 200 \text{ V}$			1.2	
Storage time		t _{stg}				3	μs
Fall time	2SC3799	$t_{\rm f}$				1	μs
	2SC3799A					1.2	







0.03 0.1

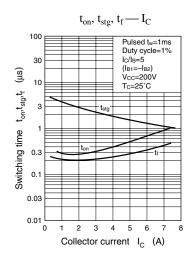
0.3 Collector current I_C

Collector to base voltage

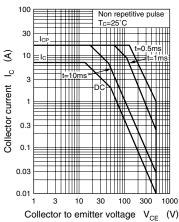
V_{CB} (V)

Collector current I_C (A)

2

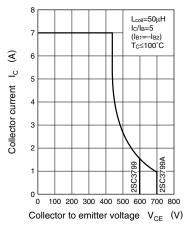


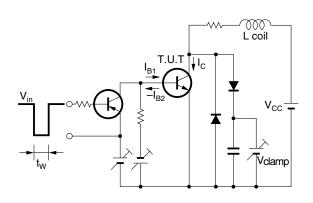
Area of safe operation (ASO)

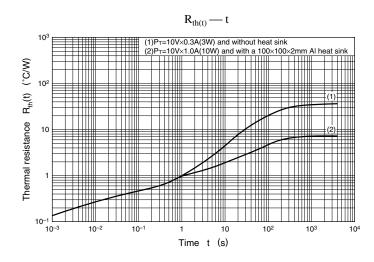


Area of safe operation, reverse bias ASO

Reverse bias ASO measuring circuit







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